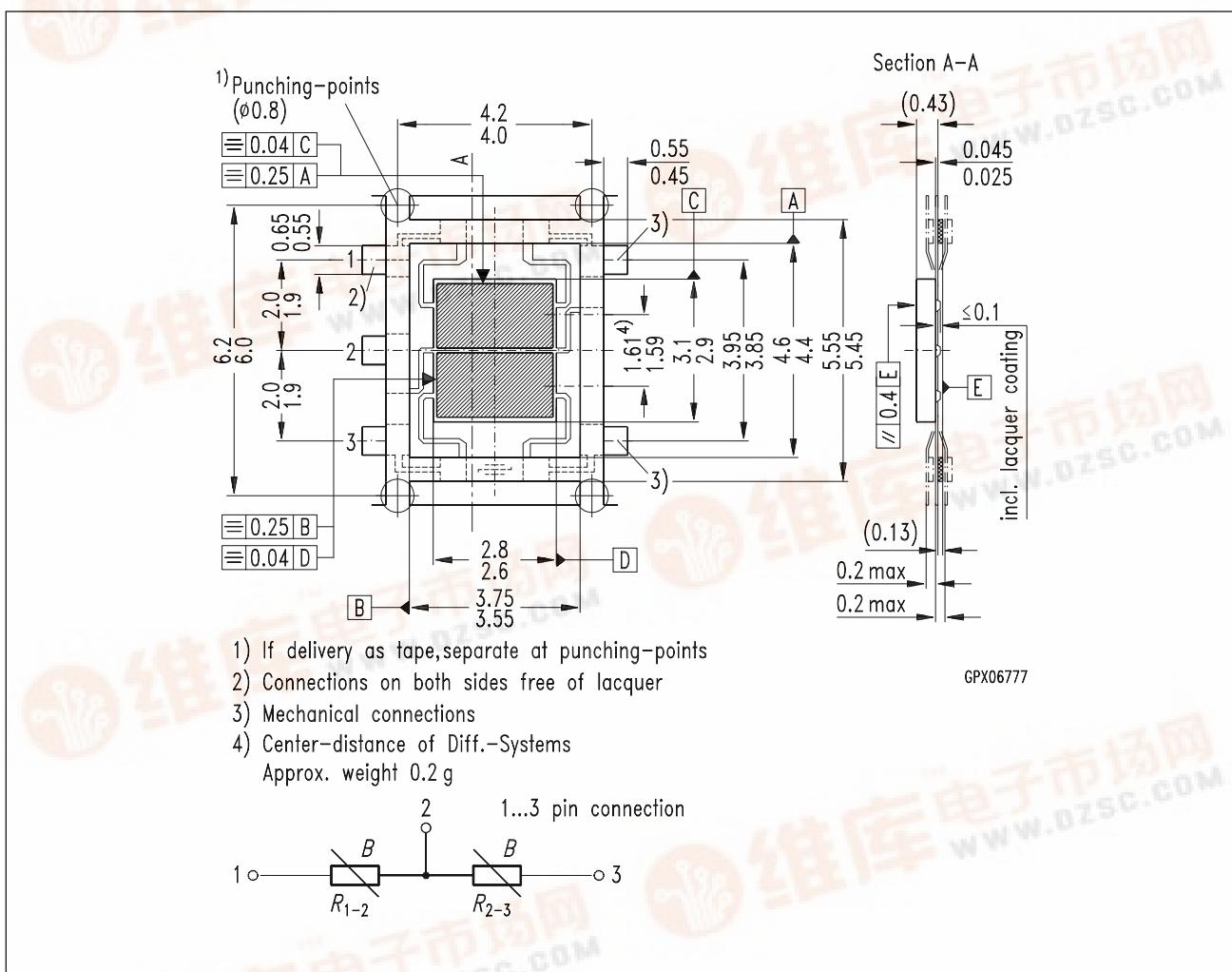


SIEMENS

Differential Magneto Resistor

FP 412 D 250



Dimensions in mm

Features

- Accurate intercenter spacing
 - High operating temperature range
 - High output voltage
 - Signal amplitude independent of speed
 - Compact construction
 - Available in strip form for automatic assembly

Typical applications

- Detection of speed
 - Detection of position
 - Detection of sense of rotation
 - Angular encoders
 - Linear position sensing

Type	Ordering Code
FP 412 D 250	Q65412-D 250

The differential magneto resistor FP 412 D 250 is a magnetically variable resistor in D-type InSb/NiSb semiconductor material. The MR is glued onto a ferrite substrate and is supplied in a "MICROPACK" copper/polyimide film package. The basic resistance of each of the magneto resistors is 250Ω . The series coupled MRs are actuated by an external magnetic field or can be biased by a permanent magnet and actuated by a soft iron target.

Maximum ratings

Parameter	Symbol	Value	Unit
Operating temperature	T_A	- 40 / +175	°C
Storage temperature	T_{stg}	- 40 / +185	°C
Power dissipation ¹⁾	P_{tot}	1000	mW
Supply voltage ²⁾ ($B = 0.2$ T)	V_{IN}	12	V
Thermal conductivity – attached to heatsink – in still air	$G_{th\ case}$ $G_{th\ A}$	≥ 25 1	mW/K mW/K

Characteristics ($T_A = 25$ °C)

Basic resistance ($I \leq 1$ mA, $B = 0$ T)	R_{01-3}	370...630	Ω
Center symmetry ³⁾	M	≤ 10	%
Relative resistance change ($R_0 = R_{01-3}$, R_{04-6} at $B = 0$ T) $B = \pm 0.3$ T ⁴⁾ $B = \pm 1$ T	R_B/R_0	> 2.8 > 12	— —
Temperature coefficient $B = 0$ T $B = \pm 0.3$ T $B = \pm 1$ T	TC_R	- 1.8 - 2.7 - 2.9	%/K %/K %/K

1) Corresponding to diagram $P_{tot} = f(T_{case})$

2) Corresponding to diagram $V_{IN} = f(T_{case})$

3)
$$M = \frac{R_{01-2} - R_{02-3}}{R_{01-2}} \times 100\% \text{ for } R_{01-2} > R_{02-3}$$

4) 1 T = 1 Tesla = 10^4 Gauss

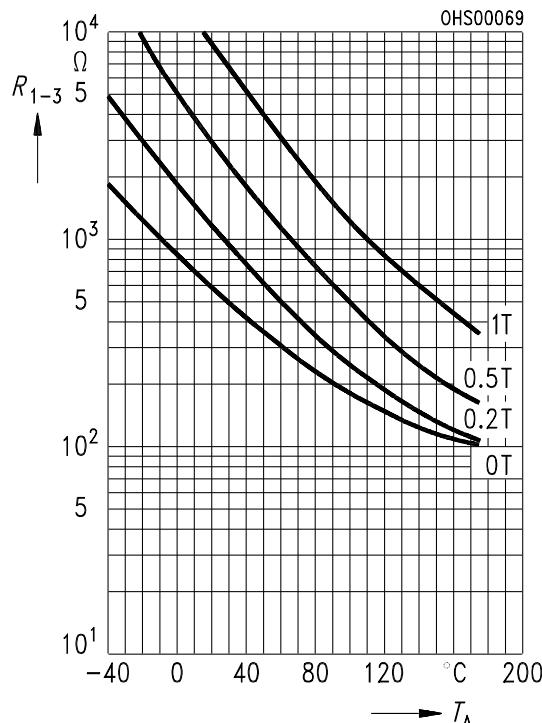
Max. power dissipation versus temperature

$$P_{\text{tot}} = f(T), T = T_{\text{case}}, T_A$$



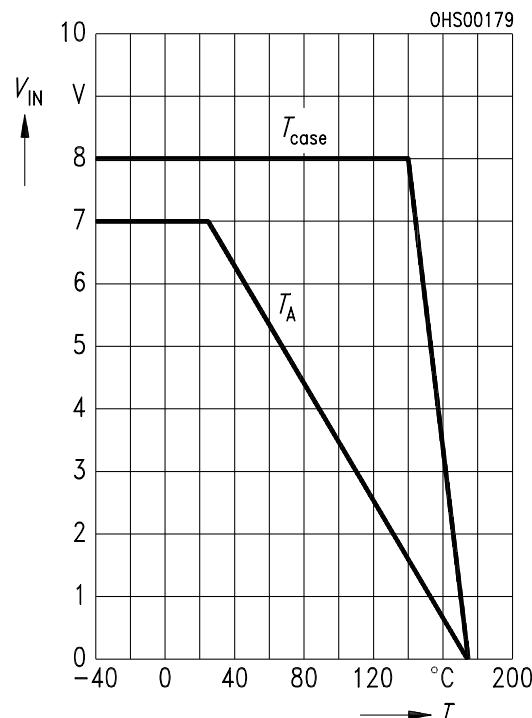
Typical MR resistance versus temperature

$$R_{1-3} = f(T_A), B = \text{Parameter}$$



Maximum supply voltage versus temperature

$$V_{\text{IN}} = f(T), B = 0.2 \text{ T} \quad T = T_{\text{case}}, T_A$$



Typical MR resistance versus magnetic induction B

$$R_{1-3} = f(B), T_A = 25^\circ\text{C}$$

